

isc Triacs

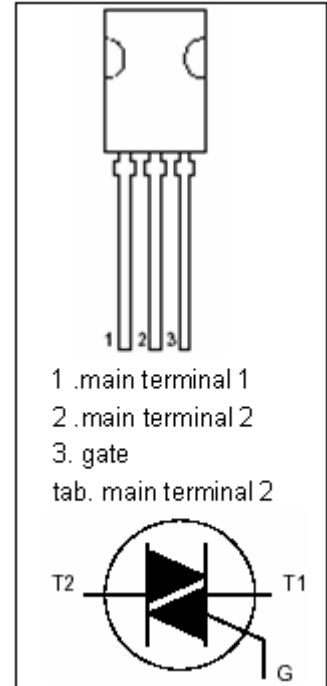
BT134-600D

FEATURES

- With TO-126P package
- Designed for use in general purpose bidirectional switching and phase control applications , which are intended to be interfaced directly to microcontrollers , logic integrated circuits and other low power gate trigger circuits.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	MIN	UNIT
V _{DRM}	Repetitive peak off-state voltage	600	V
V _{RRM}	Repetitive peak off-state voltage	600	V
I _{T(RMS)}	RMS on-state current (full sine wave)	4	A
I _{TSM}	Non-repetitive peak on-state current	25	A
P _{GM}	Peak gate power dissipation	5	W
P _{G(AV)}	Average gate power dissipation	0.5	W
T _j	Operating junction temperature	110	°C
T _{stg}	Storage temperature	-45~150	°C



ELECTRICAL CHARACTERISTICS (T_C=25°C unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
I _{RRM}	Repetitive peak reverse current	V _R =V _{RRM} , V _R =V _{RRM} , T _J =110°C		0.01 0.2	mA
I _{DRM}	Repetitive peak off-state current	V _D =V _{DRM} , V _D =V _{DRM} , T _J =110°C		0.01 0.2	mA
I _{GT}	Gate trigger current	V _D =12V; I _T = 0.1A, R _L = 30 Ω	I	5	mA
			II	5	
			III	5	
			IV	10	
V _{TM}	On-state voltage	I _T = 5A		1.7	V
I _H	Holding current	I _{GT} = 0.1A, V _D = 12V		10	mA
V _{GT}	Gate trigger voltage	V _D =12V; R _L = 30 Ω		1.5	V